INTEGRATED CIRCUITS

DATA SHEET

LM111/211/311/311B Voltage comparator

Product data Supersedes data of 1994 Aug 31 File under Integrated Circuits, IC11 Handbook 2001 Aug 03





Voltage comparator

LM111/211/311/311B

DESCRIPTION

The LM111 series are voltage comparators that have input currents approximately a hundred times lower than devices like the $\mu A710$. They are designed to operate over a wider range of supply voltages; from standard ± 15 V op amp supplies down to a single 3 V supply. Their output is compatible with RTL, DTL, and TTL as well as MOS circuits. Further, they can drive lamps or relays, switching voltages up to 50 V at currents as high as 50mA.

Both the inputs and the outputs of the LM111 series can be isolated from system ground, and the output can drive loads referred to ground, the positive supply, or the negative supply. Offset balancing and strobe capability are provided and outputs can be wire-ORed.

Although slower than the μ A710 (200 ns response time versus 40 ns), the devices are also much less prone to spurious oscillations. The LM111 series has the same pin configuration as the μ A710 series.

FEATURES

• Operates from single 3 V supply (LM311B)

• Maximum input bias current: 150 nA (LM311: 250 nA)

Maximum offset current: 20 nA (LM311: 50 nA)

Differential input voltage range: ±30 V

Power consumption: 135 mW at ±15 V

High sensitivity: 200 V/mVZero crossing detector

PIN CONFIGURATION

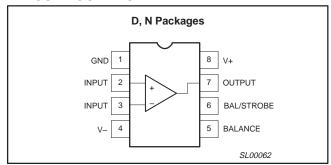


Figure 1. Pin Configuration

APPLICATIONS

- Precision squarer
- Positive/negative peak detector
- Low voltage adjustable reference supply
- Switching power amplifier

ORDERING INFORMATION

DESCRIPTION	TEMPERATURE RANGE	ORDER CODE	DWG#
8-Pin Plastic Small Outline Package (SO)	−55 °C to +125 °C	LM111D	SOT96-1
8-Pin Plastic Dual In-Line Package (DIP)	−55 °C to +125 °C	LM111N	SOT97-1
8-Pin Plastic Small Outline Package (SO)	−25 °C to +85 °C	LM211D	SOT96-1
8-Pin Plastic Dual In-Line Package (DIP)	−25 °C to +85 °C	LM211N	SOT97-1
8-Pin Plastic Small Outline Package (SO)	0 °C to +70 °C	LM311D	SOT96-1
8-Pin Plastic Dual In-Line Package (DIP)	0 °C to +70 °C	LM311N	SOT97-1
8-Pin Plastic Small Outline Package (SO)	0 °C to +70 °C	LM311BD	SOT96-1
8-Pin Plastic Dual In-Line Package (DIP)	0 °C to +70 °C	LM311BN	SOT97-1

Voltage comparator

LM111/211/311/311B

EQUIVALENT SCHEMATIC

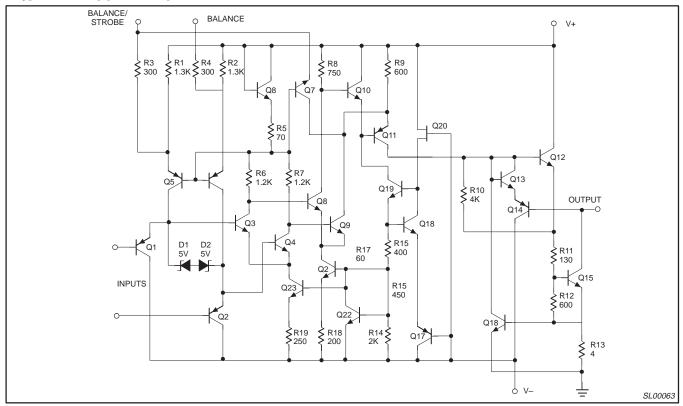


Figure 2. Equivalent Schematic

ABSOLUTE MAXIMUM RATINGS

SYMBOL	PARAMETER	RATING	UNIT
V _S	Total supply voltage	36	V
	Output to negative supply voltage: LM111/LM211	50	V
	LM311/LM311B	40	V
	Ground to negative supply voltage	30	V
	Differential input voltage	±30	V
V _{IN}	Input voltage ¹	±15	V
P _{D MAX}	Maximum power dissipation, T _{amb} = 25 °C (still-air) ² N package D package	1190 780	mW mW
I	Output short-circuit duration	10	sec
T _{amb}	Operating ambient temperature range LM111 LM211 LM311/LM311B	-55 to +125 -25 to +85 0 to +70	့ လ ့င
T _{stg}	Storage temperature range	-65 to +150	°C
T _{sld}	Lead soldering temperature (10 sec max)	230	°C

NOTES:

- 1. This rating applies for ±15 V supplies. The positive input voltage limit is 30 V above the negative supply. The negative input voltage limit is equal to the negative supply voltage or 30 V below the positive supply, whichever is less.
- 2. Derate above 25 °C, at the following rates:
 - N package at 9.5 mW/°C
 - D package at 6.2 m/W°C

Voltage comparator

LM111/211/311/311B

DC ELECTRICAL CHARACTERISTICS^{1, 2, 3, 6}

Over temperature range unless otherwise specified.

OVMDOL	DADAMETED	TEGT COMPITIONS	LM	111/LM	211		LM311			LM311B	3	
SYMBOL	PARAMETER	TEST CONDITIONS	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	UNIT
V _{OS}	Input offset voltage ³	$T_{amb} = 25 ^{\circ}C;$ $R_{S} \le 50 k\Omega$		0.7	3.0		2.0	7.5		2.0	7.5	mV
Ios	Input offset current ³	T _{amb} = 25 °C		4.0	10		6.0	50		6	25	nA
I _{BIAS}	Input bias current	T _{amb} = 25 °C		60	100		100	250		100	200	nA
A _V	Voltage gain	T _{amb} = 25 °C		200			200			200		V/mV
	Response time ⁴	T _{amb} = 25 °C		200			200			500		ns
V _{SAT}	Saturation voltage	$\begin{split} & LM111/211 \ V_{IN} \le -5mV; \\ & I_{OUT} = 50 \ mA \\ & LM311/B \ V_{IN} \le -10 \ mV; \\ & I_{OUT} = 50 \ mA \\ & T_{amb} = 25 \ ^{\circ}C \end{split}$		0.75	1.5		0.75	1.5		0.75	1.5	V
I _{BAL/STR}	Strobe on current	T _{amb} = 25 °C		3.0			3.0			3.0		mA
I _{LEAKAGE}	Output leakage current ⁶	$\begin{split} &LM111/211 \ V_{IN} \geq 5 \ mV; \\ &V_{OUT} = 35 \ V \\ &LM311/B \ V_{IN} \geq 10 \ mV; \\ &V_{OUT} = 35 \ V \\ &T_{amb} = 25 \ ^{\circ}C, \\ &I_{STROBE} = 3 \ mA \\ &(V-=V_{GND} = -5 \ V) \end{split}$		0.2	10		0.2	50		0.2	50	nA
Vos	Input offset voltage ³	R _S ≤ 50 kΩ			4.0			10			10	mV
Ios	Input offset current ³				20			70			50	nA
I _{BIAS}	Input bias current				150			300			250	nA
V _{IN}	Input voltage range	V = ±15 V (Pin 7 may go to 5 V)	-14.5	13.8 to –14.7	13.0	-14.5	13.8 to –14.7	13.0	V- +0.5		V+ -1.5	V
V _{OL}	Saturation voltage ⁶	$\begin{array}{c} V+ \geq 4.5 \; V, \; V-=0 \; V \\ LM111/211 \; V_{IN} \leq -6 \; mV; \\ I_{SINK} \leq 8 \; mA \\ LM311/B \; V_{IN} \leq -10 \; mV; \\ I_{SINK} \leq 8 \; mA \end{array}$		0.23	0.4		0.23	0.4		0.23	0.4	V
I _{OH}	Output leakage current	$V_{IN} \ge 5 \text{ mV};$ $V_{OUT} = 35 \text{ V}$		0.1	0.5							μА
I _{CC}	Positive supply current	T _{amb} = 25 °C		5.1	6.0		5.1	7.5		1.6	3.5	mA
I _{EE}	Negative supply voltage	T _{amb} = 25 °C		4.1	5.0		4.1	5.0				mA

NOTES

- 1. This rating applies for ±15 V supplies. The positive input voltage limit is 30 V above the negative supply. The negative input voltage limit is equal to the negative supply voltage or 30 V below the positive supply, whichever is less.
- 2. These specifications apply for V_S = ±15 V and 0 °C < T_{amb} < 70 °C unless otherwise specified. With the LM211, however, all temperature specifications are limited to −25 °C ≤ T_{amb} ≤ +85 °C, and for the LM111 is limited to −55 °C < T_{amb} < +125 °C. The offset voltage, offset current, and bias current specifications apply for any supply voltage from a single 5 V supply up to ±15 V supplies.
- 3. The offset voltages and offset currents given are the maximum values required to drive the output within a volt of either supply with 1 mA load. Thus, these parameters define an error band and take into account the worst case effects of voltage gain and input impedance.
- 4. The response time specified is for a 100 mV input step with 5 mV over-drive.
- 5. Do not short the strobe pin to ground; it should be current driven at 3 mA to 5 mA.
- 6. LM311B, all parameters are at V+ = 3 V \pm 10%; V- = GND = 0 V.

2001 Aug 03

Voltage comparator

LM111/211/311/311B

TYPICAL APPLICATIONS

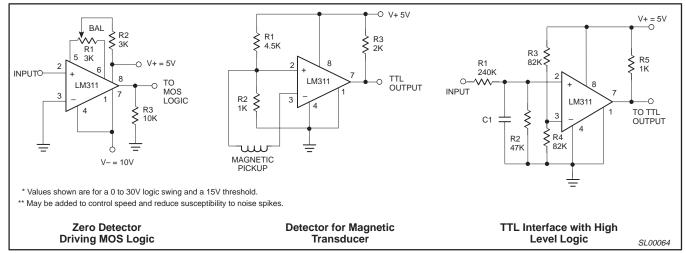


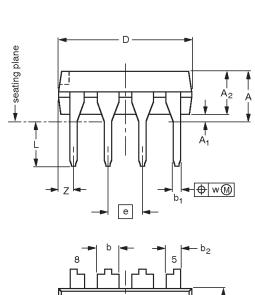
Figure 3. Typical Applications

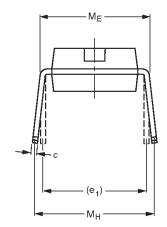
Voltage comparator

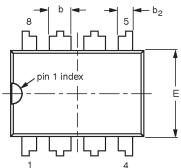
LM111/211/311/311B

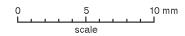
DIP8: plastic dual in-line package; 8 leads (300 mil)

SOT97-1









DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	A ₁ min.	A ₂ max.	b	b ₁	b ₂	O	D ⁽¹⁾	E ⁽¹⁾	е	e ₁	L	ME	Мн	w	Z ⁽¹⁾ max.
mm	4.2	0.51	3.2	1.73 1.14	0.53 0.38	1.07 0.89	0.36 0.23	9.8 9.2	6.48 6.20	2.54	7.62	3.60 3.05	8.25 7.80	10.0 8.3	0.254	1.15
inches	0.17	0.020	0.13	0.068 0.045	0.021 0.015	0.042 0.035	0.014 0.009	0.39 0.36	0.26 0.24	0.10	0.30	0.14 0.12	0.32 0.31	0.39 0.33	0.01	0.045

Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

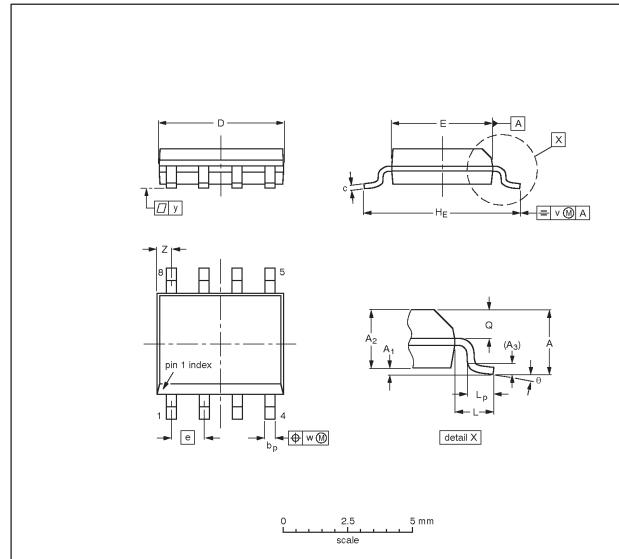
OUTLINE		REFER	RENCES	EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE
SOT97-1	050G01	MO-001	SC-504-8			95-02-04 99-12-27

Voltage comparator

LM111/211/311/311B

SO8: plastic small outline package; 8 leads; body width 3.9 mm

SOT96-1



DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	Α1	A ₂	A ₃	bр	С	D ⁽¹⁾	E ⁽²⁾	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ
mm	1.75	0.25 0.10	1.45 1.25	0.25	0.49 0.36	0.25 0.19	5.0 4.8	4.0 3.8	1.27	6.2 5.8	1.05	1.0 0.4	0.7 0.6	0.25	0.25	0.1	0.7 0.3	8°
inches	0.069	0.010 0.004	0.057 0.049	0.01		0.0100 0.0075	0.20 0.19	0.16 0.15	0.050	0.244 0.228	0.041	0.039 0.016		0.01	0.01	0.004	0.028 0.012	0°

Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	ENCES	EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	EIAJ	PROJECTION	1330E DATE
SOT96-1	076E03	MS-012			97-05-22 99-12-27

Voltage comparator

LM111/211/311/311B

Data sheet status

Data sheet status ^[1]	Product status ^[2]	Definitions
Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
Preliminary data	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product.
Product data	Production	This data sheet contains data from the product specification. Philips Semiconductors reserves the right to make changes at any time in order to improve the design, manufacturing and supply. Changes will be communicated according to the Customer Product/Process Change Notification (CPCN) procedure SNW-SQ-650A.

^[1] Please consult the most recently issued data sheet before initiating or completing a design.

Definitions

Short-form specification — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

Application information — Applications that are described herein for any of these products are for illustrative purposes only. Philips Semiconductors make no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Disclaimers

Life support — These products are not designed for use in life support appliances, devices or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips Semiconductors customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips Semiconductors for any damages resulting from such application.

Right to make changes — Philips Semiconductors reserves the right to make changes, without notice, in the products, including circuits, standard cells, and/or software, described or contained herein in order to improve design and/or performance. Philips Semiconductors assumes no responsibility or liability for the use of any of these products, conveys no license or title under any patent, copyright, or mask work right to these products, and makes no representations or warranties that these products are free from patent, copyright, or mask work right infringement, unless otherwise specified.

Contact information

For additional information please visit

http://www.semiconductors.philips.com. Fax: +31 40 27 24825

For sales offices addresses send e-mail to: sales.addresses@www.semiconductors.philips.com

© Koninklijke Philips Electronics N.V. 2001 All rights reserved. Printed in U.S.A.

Date of release: 12-01

Document order number: 9397 750 09216

Let's make things better.

Philips Semiconductors





^[2] The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL http://www.semiconductors.philips.com.